# UP04311

## Silicon NPN epitaxial planar transistor (Tr1) Silicon PNP epitaxial planar transistor (Tr2)

#### For switching For digital circuits

#### Features

- Two elements incorporated into one package (Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

#### Basic Part Number of Element

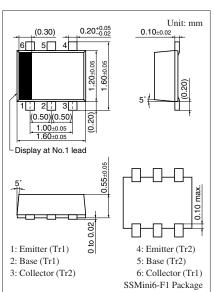
• UNR2211 (UN2211) + UNR2111 (UN2111)

#### Parameter Symbol Unit Rating Tr1 Collector to base voltage 50 V V<sub>CBO</sub> V Collector to emitter voltage V<sub>CEO</sub> 50 Collector current $I_C$ 100 mА Tr2 -50 V Collector to base voltage $V_{CBO}$ Collector to emitter voltage -50 V V<sub>CEO</sub> -100Collector current $I_{C}$ mA 125 Overall Total power dissipation $P_T$ mW 125 °C Junction temperature Ti -55 to +125 °C Storage temperature Tstg

### Absolute Maximum Ratings $T_a = 25^{\circ}C$

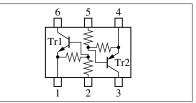
#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

#### • Tr1



#### Marking Symbol: 7X

#### Internal Connection



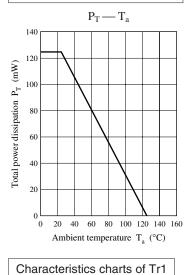
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector to base voltage	V <sub>CBO</sub>	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	50			V
Collector to emitter voltage	V <sub>CEO</sub>	$I_{\rm C} = 2 \text{ mA}, I_{\rm B} = 0$	50			V
Collector cutoff current	I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μΑ
	I <sub>CEO</sub>	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	
Emitter cutoff current	I <sub>EBO</sub>	$V_{EB} = 6 V, I_C = 0$			0.5	mA
Forward current transfer ratio	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$	35			
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.3 \text{ mA}$			0.25	V
High-level output voltage	V <sub>OH</sub>	$V_{CC} = 5 \text{ V}, \text{ V}_{B} = 0.5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega$	4.9			V
Low-level output voltage	V <sub>OL</sub>	$V_{CC} = 5 \text{ V}, \text{ V}_{B} = 2.5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega$			0.2	V
Input resistance	R <sub>1</sub>		-30%	10	+30%	kΩ
Resistance ratio	R <sub>1</sub> /R <sub>2</sub>		0.8	1.0	1.2	
Transition frequency	f <sub>T</sub>	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

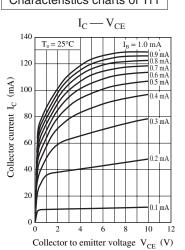
Note) The part number in the parenthesis shows conventional part number.

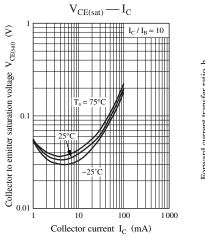
### $\blacksquare$ Electrical Characteristics (continued) $T_a = 25^\circ C \pm 3^\circ C$

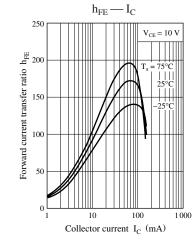
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector to base voltage	V <sub>CBO</sub>	$I_{\rm C} = -10 \ \mu A, \ I_{\rm E} = 0$	-50			V
Collector to emitter voltage	V <sub>CEO</sub>	$I_{\rm C} = -2  {\rm mA},  I_{\rm B} = 0$	-50			V
Collector cutoff current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$			- 0.1	μΑ
	I <sub>CEO</sub>	$V_{CE} = -50 \text{ V}, I_B = 0$			- 0.5	
Emitter cutoff current	I <sub>EBO</sub>	$V_{EB} = -6 V, I_C = 0$			- 0.5	mA
Forward current transfer ratio	$h_{FE}$	$V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$	35			
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = -0.3 \text{ mA}$			- 0.25	V
High-level output voltage	V <sub>OH</sub>	$V_{CC} = -5 \text{ V},  V_{B} = -0.5  \text{V},  \text{R}_{L} = 1  \text{k}\Omega$	-4.9			V
Low-level output voltage	V <sub>OL</sub>	$V_{CC} = -5 \text{ V},  \text{V}_{B} = -2.5  \text{V},  \text{R}_{L} = 1  \text{k}\Omega$			- 0.2	V
Input resistance	R <sub>1</sub>		-30%	10	+30%	kΩ
Resistance ratio	R <sub>1</sub> /R <sub>2</sub>		0.8	1.0	1.2	
Transition frequency	$f_{T}$	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz

#### Common characteristics chart

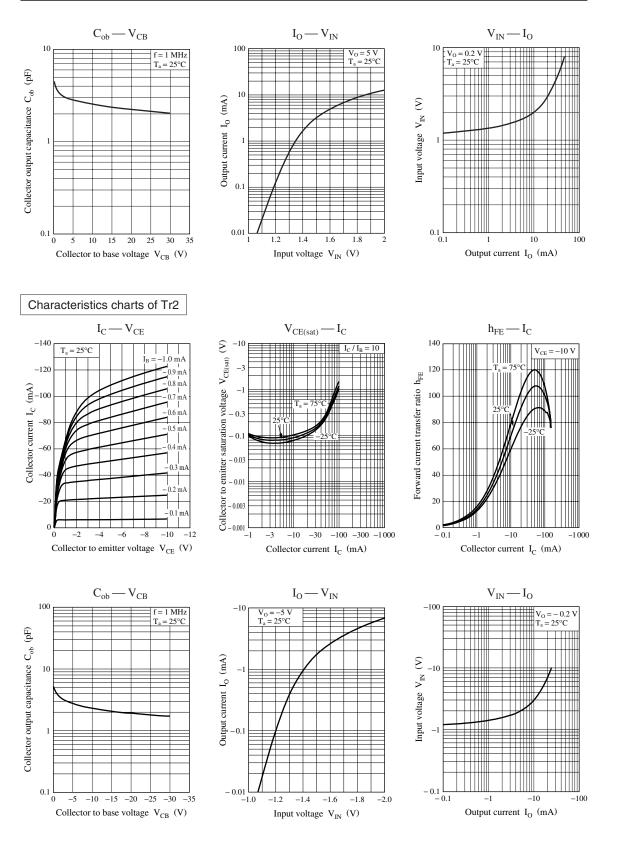








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